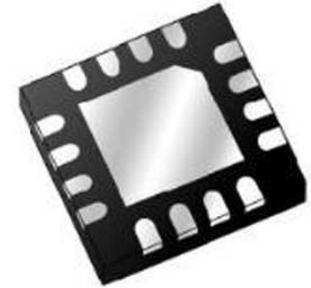


Dual DPDT Low RON, Low Capacitance Switch, Analog Switch ICs DUAL LOW RON SWITCH DPDT

Manufacturers	ON Semiconductor, LLC
Package/Case	QFN16
Product Type	Interface ICs
RoHS	Rohs
Lifecycle	



Images are for reference only

Please submit RFQ for NLAS3899BMNTBG or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

The NLAS3899B is a dual DPDT analog switch designed for low power audio and dual SIM card applications. The low RON of 3.0 Ω (typical) is ideal for routing audio signals to or from a moderately high impedance load. In addition, the low CON of 20 pF (typical) gives the NLAS3899B a high bandwidth of 280 MHz, perfect for dual SIM card applications.

Features

- Single Supply Operation; 1.65 to 4.3 V VCC
- Low ON Resistance (3.0 Ω Typical Across VCC)
- Low CON (20 pF Typical)
- Bandwidth 280 MHz
- Maximum Breakdown Voltage: 5.5 V
- Low Static Power
- Interfaces with 1.8 V Chipset

Application

ONSEMI

Related Products



[NLAS3899BMNTXG](#)

ON Semiconductor, LLC
QFN-16



[NLAS4053DTR2](#)

ON Semiconductor, LLC
SSOP-16



[NLVASB3157DFT2G](#)

ON Semiconductor, LLC
SC-70-6



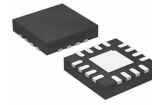
[NLAST4051DTR2G](#)

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